

# Quadruple 2-Line to 1-Line Data Select RS/Multiplexers With 3-State Outputs

## 1 Features

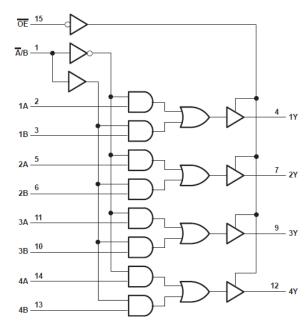
- Operating voltage range of 4.5 V to 5.5 V
- High-current3-state outputs interface directly with system bus
- Typical  $t_{pd} = 17 \text{ ns}$
- Low power consumption, 80-µA max I<sub>CC</sub>
- ±6-mA output drive at 5 V
- Low input current of 1 µA max
- Inputs are TTL-voltage compatible
- Provide bus interface from multiple sources in high-performance systems
- Buffered inputs and outputs

## 2 Description

The 'HCT257 devices are designed to multiplex signals from 4-bit data sources to 4-output data lines in bus-organized systems.

#### **Device Information**

ORDERABLE PART NUMBER	PACKAGE	BODY SIZE (NOM)
SN74HCT257	N (PDIP, 16)	19.31 mm × 6.35 mm
311/4/10/23/	D (SOIC, 16)	9.90 mm × 3.90 mm
SNJ54HCT257	J (CDIP, 16)	24.38 mm × 6.92 mm



Pin numbers shown are for the D, J, and N packages.

Logic Diagram (Positive Logic)



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## **3 Revision History**

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

## Changes from Revision D (September 2003) to Revision E (July 2022)

Page

 Updated the numbering, formatting, tables, figures, and cross-references throughout the document to reflect modern data sheet standards......



# **4 Pin Configuration and Functions**

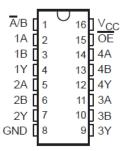


Figure 4-1. J, N and D Package 16-Pin CDIP, PDIP or SOIC Top View

## **Pin Functions**

PI	PIN			
SOIC or TSSOP NO.	NAME	I/O <sup>(1)</sup>	DESCRIPTION	
1	Ā/B	I	Address select	
2	1A	I	Channel 1, data input A	
3	1B	I	Channel 1, data input B	
4	1Y	I	Channel 1, data output	
5	2A	0	Channel 2, data input A	
6	2B	0	Channel 2, data input B	
7	2Y	I	Channel 2, data output	
8	GND	_	Ground	
9	3Y	I	Channel 3, data output	
10	3B	I	Channel 3, data input B	
11	3A	I	Channel 3, data input A	
12	4Y	I	Channel 4, data output	
13	4B	I	Channel 4, data input B	
14	4A	I	Channel 4, data input A	
15	G	I	Output strobe, active low	
16	V <sub>CC</sub>	_	Positive supply	



## **5 Specifications**

## 5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1)

			MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage range		-0.5	7	V
I <sub>IK</sub>	Input clamp current <sup>(2)</sup>	$V_I < 0$ or $V_I > V_{CC}$		±20	mA
I <sub>OK</sub>	Output clamp current <sup>(2)</sup>	$V_O < 0$ or $V_O > V_{CC}$		±20	mA
Io	Continuous output current	$V_O = 0$ to $V_{CC}$		±35	mA
	Continuous current through V <sub>CC</sub> or GND	·		±70	mA
TJ	Junction Temperature			150	°C
T <sub>stg</sub>	Storage temperature range		-65	150	°C

<sup>1)</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

## **5.2 Recommended Operating Conditions**(1)

			SN	54HCT257		SN74HCT257			UNIT
			MIN	NOM	MAX	MIN	NOM	MAX	UNII
V <sub>CC</sub>	Supply voltage		4.5	5	5.5	4.5	5	5.5	V
V <sub>IH</sub>	High-level input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V	2			2			V
V <sub>IL</sub>	Low-level input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V			0.8			0.8	V
VI	Input voltage		0		V <sub>CC</sub>	0		V <sub>CC</sub>	V
Vo	Output voltage		0		V <sub>CC</sub>	0		V <sub>CC</sub>	V
t <sub>t</sub>	Input transition (rise and fall			500			500	ns	
T <sub>A</sub>	Operating free-air temperatu	-55		125	-40		85	°C	

<sup>(1)</sup> All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

#### **5.3 Thermal Information**

		D (SOIC)	N (PDIP)	
THERMAL METRI	С	16 PINS	16 PINS	UNIT
$R_{\theta JA}$	Package thermal impedance	73	67	°C/W

#### 5.4 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS		T <sub>A</sub> = 25°C		SN54HCT25 7		SN74HCT25 7		UNIT	
	CONDIT			MIN	TYP	MAX	MIN	MAX	MIN	MAX	
Va High level output voltage		I <sub>OH</sub> = -20 μΑ	4.5 V	4.4	4.499		4.4		4.4		V
V <sub>OH</sub> High level output voltage	V <sub>IL</sub>	I <sub>OH</sub> = -6 mA	=   4.5 v	3.98	4.3		3.7		3.84		
V <sub>OL</sub> L Low level output voltage	V <sub>I</sub> = V <sub>IH</sub> or	I <sub>OL</sub> = 20 μA	4.5 V		0.001	0.1		0.1		0.1	V
VOL 2 20W 16V61 Sulput Voltage	V <sub>IL</sub>	I <sub>OL</sub> = 6 mA	7.5 V		0.17	0.26		0.4		0.33	

<sup>(2)</sup> The input and output voltage ratings may be exceeded if the input and output current ratings are observed.



## 5.4 Electrical Characteristics (continued)

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		AMETER TEST CONDITIONS		V <sub>cc</sub>	T <sub>A</sub> = 25°C			SN54HCT25 7		SN74HCT25 7		UNIT
			IONS		MIN	TYP	MAX	MIN	MAX	MIN	MAX	
I <sub>I</sub>	Input leakage current	V <sub>I</sub> = V <sub>CC</sub> or	0 0	5.5 V		±0.1	±100		±1000		±1000	nA
I <sub>OZ</sub>	Off-State (High-Impedance State) Output Current	V <sub>O</sub> = V <sub>CC</sub> or 0,	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>	5.5 V		±0.01	±0.5		±10		±5	μА
I <sub>CC</sub>	Supply current	$V_I = V_{CC}$ or 0,	I <sub>O</sub> = 0	5.5 V			8		160		80	μΑ
ΔI <sub>CC</sub> <sup>(2)</sup>	Supply-Current Change	One input a V or 2.4 V, Other input or V <sub>CC</sub>		5.5 V		1.4	2.4		3		2.9	mA
C <sub>i</sub>	Input Capacitance			4.5 V to 5.5 V		3	10		10 <sup>(1)</sup>		10	pF

<sup>(1)</sup> On products compliant to MIL-PRF-38535, this parameter is not production tested.

## 5.5 Switching Characteristics

over recommended operating free-air temperature range, C<sub>L</sub> = 50 pF (unless otherwise noted) (see Figure 6-1)

DADAMETED	PARAMETER FROM		V	TA	= 25°C		SN54HCT25	7	SN74HCT257	UNIT
(INP	(INPUT)	(OUTPUT)	V <sub>CC</sub>	MIN	TYP	MAX	MIN N	IAX	MIN MAX	UNII
A or I	A or B	Υ	4.5 V		20	30		45	38	
	AOID	'	5.5 V		17	27		40	34	ns
t <sub>pd</sub>	Δ/R	Ā/B Y	4.5 V		20	30		45	38	113
	AD		5.5 V		17	27		40	34	
	ŌĒ	Y	4.5 V		20	30		45	38	ns
en	<u> </u>	<b>'</b>	5.5 V		17	27		40	34	113
t <sub>dis</sub>	ŌĒ	Y	4.5 V		20	30		45	38	ns
dis	idis OL	OL 1	5.5 V		17	27		40	34	110
t <sub>t</sub>		Any	4.5 V		8	15		22	19	ns
प्		, ary	5.5 V		7	14		21	17	113

## **5.6 Switching Characteristics**

over recommended operating free-air temperature range, C<sub>1</sub> = 150 pF (unless otherwise noted) (see Figure 6-1)

PARAMETER	FROM	то	Vc	T <sub>A</sub>	λ = 25°C		SN54HCT	257	SN74HC	T257	UNIT	
PARAMETER	(INPUT)	(OUTPUT)	<b>v</b> C	MIN	TYP	MAX	MIN	MAX	MIN	MAX	ONII	
	A or B	Υ	4.5 V		22	38		57		48		
	AOID	ĭ	5.5 V		19	35		53		44	no	
t <sub>pd</sub>	Ā/B	В Ү	4.5 V		22	38		57		48	ns	
	A/D		5.5 V		19	35		53		44		
+	ŌĒ	V	4.5 V		23	40		60		50	ns	
<sup>L</sup> en	t <sub>en</sub> OE	OE Y	ı	5.5 V		20	38		57		48	115
4		Any	4.5 V		17	42		63	-	53	ns	
t <sub>t</sub>		Any	5.5 V		14	38		57		48	115	

<sup>(2)</sup> This is the increase in supply current for each input that is at one of the specified TTL voltage levels, rather than 0 V or V<sub>CC</sub>.



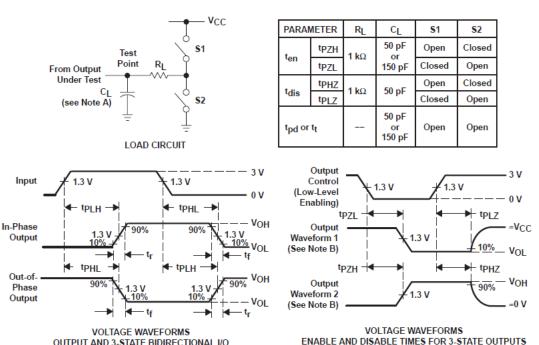
# **5.7 Operating Characteristics**

T<sub>A</sub> 25°C

PARAMETER		TEST CONDITIONS	TYP	UNIT
C <sub>pd</sub>	Power dissipation capacitance	No load	13	pF



### **6 Parameter Measurement Information**



- C<sub>L</sub> includes probe and test-fixture capacitance.
- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. Phase relationships between waveforms were chosen arbitrarily. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  1 MHz,  $Z_0 = 50 \Omega$ ,  $t_r = 6 \text{ ns}$ ,  $t_f = 6 \text{ ns}$ .
- D. The outputs are measured one at a time with one input transition per measurement.

OUTPUT AND 3-STATE BIDIRECTIONAL I/O PROPAGATION DELAY TIME

- E.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
- F. t<sub>PZL</sub> and t<sub>PZH</sub> are the same as t<sub>en</sub>.
- G. t<sub>PLH</sub> and t<sub>PHL</sub> are the same as t<sub>pd</sub>.

Figure 6-1. Load Circuit and Voltage Waveforms

## 7 Detailed Description

## 7.1 Overview

The 'HCT257 devices are designed to multiplex signals from 4-bit data sources to 4-output data lines in busorganized systems. The 3-state outputs do not load the data lines when the output-enable ( $\overline{OE}$ ) input is at the high logic level.

To ensure the high-impedance state during power up or power down,  $\overline{OE}$  should be tied to  $V_{CC}$  through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

## 7.2 Functional Block Diagram

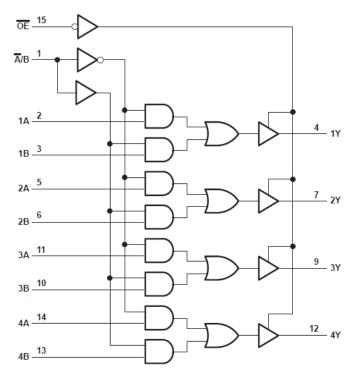


Figure 7-1. Function Diagram



## **8 Device Functional Modes**

**Table 8-1. Function Table** 

	INPUTS (1)									
ŌĒ	SELECT	DA	TA	OUTPUT <sup>(2)</sup> Y						
OE.	Ā/B	A	В	·						
Н	X	X	X	Z						
L	L	L	X	L						
L	L	Н	X	Н						
L	Н	X	L	L						
L	Н	X	Н	Н						

<sup>(1)</sup> H = High Voltage Level, L = Low Voltage Level, X = Don't Care

<sup>(2)</sup> H = Driving High, L = Driving Low, Z = High Impedance State



## 9 Power Supply Recommendations

The power supply can be any voltage between the minimum and maximum supply voltage rating located in the *Recommended Operating Conditions*. Each  $V_{CC}$  terminal should have a good bypass capacitor to prevent power disturbance. A 0.1- $\mu$ F capacitor is recommended for this device. It is acceptable to parallel multiple bypass caps to reject different frequencies of noise. The 0.1- $\mu$ F and 1- $\mu$ F capacitors are commonly used in parallel. The bypass capacitor should be installed as close to the power terminal as possible for best results.

### 10 Layout

### 10.1 Layout Guidelines

When using multiple-input and multiple-channel logic devices inputs must not ever be left floating. In many cases, functions or parts of functions of digital logic devices are unused; for example, when only two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used. Such unused input pins must not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. All unused inputs of digital logic devices must be connected to a logic high or logic low voltage, as defined by the input voltage specifications, to prevent them from floating. The logic level that must be applied to any particular unused input depends on the function of the device. Generally, the inputs are tied to GND or  $V_{CC}$ , whichever makes more sense for the logic function or is more convenient.



## 11 Device and Documentation Support

TI offers an extensive line of development tools. Tools and software to evaluate the performance of the device, generate code, and develop solutions are listed below.

### 11.1 Documentation Support

#### 11.1.1 Related Documentation

### 11.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

## 11.3 Support Resources

TI E2E<sup>™</sup> support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

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#### 11.4 Trademarks

TI E2E™ is a trademark of Texas Instruments.

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### 11.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

#### 11.6 Glossary

TI Glossary

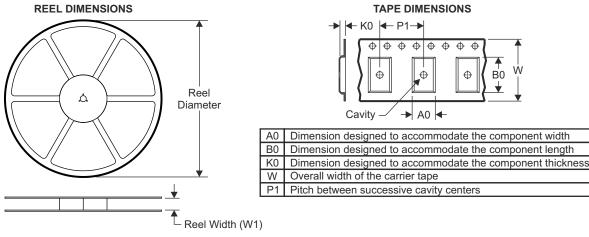
This glossary lists and explains terms, acronyms, and definitions.

## 12 Mechanical, Packaging, and Orderable Information

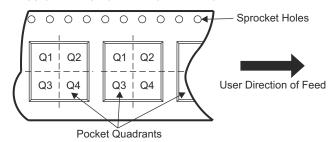
The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



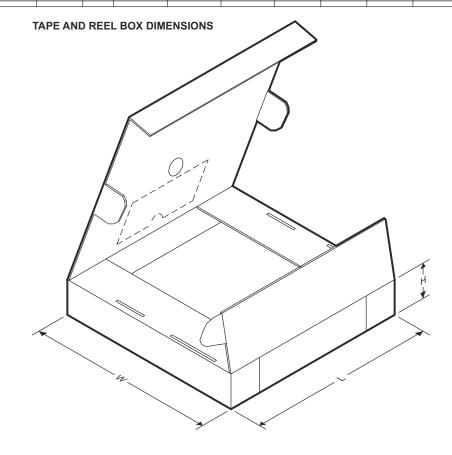
## 12.1 Tape and Reel Information



### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



	Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant	
--	--------	-----------------	--------------------	------	-----	--------------------------	--------------------------	------------	------------	------------	------------	-----------	------------------	--





Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
			1				

## 12.2 Mechanical Data

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#### PACKAGING INFORMATION

Orderable part number	Status	Material type	Package   Pins	Package qty   Carrier	RoHS	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
	(1)	(2)			(0)	(4)	(5)		(0)
SN74HCT257D	Obsolete	Production	SOIC (D)   16	-	-	Call TI	Call TI	-40 to 85	HCT257
SN74HCT257DR	Active	Production	SOIC (D)   16	2500   LARGE T&R	Yes	NIPDAU   SN	Level-1-260C-UNLIM	-40 to 85	HCT257
SN74HCT257DR.A	Active	Production	SOIC (D)   16	2500   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HCT257
SN74HCT257N	Active	Production	PDIP (N)   16	25   TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 85	SN74HCT257N
SN74HCT257N.A	Active	Production	PDIP (N)   16	25   TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 85	SN74HCT257N

<sup>(1)</sup> Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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<sup>(3)</sup> RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

<sup>(4)</sup> Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

<sup>(5)</sup> MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

<sup>(6)</sup> Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

# **PACKAGE MATERIALS INFORMATION**

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## TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74HCT257DR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1

# **PACKAGE MATERIALS INFORMATION**

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### \*All dimensions are nominal

	Device	Package Type Package Drawing		Pins SPQ		Length (mm)	Width (mm)	Height (mm)	
I	SN74HCT257DR	SOIC	D	16	2500	353.0	353.0	32.0	

# **PACKAGE MATERIALS INFORMATION**

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## **TUBE**



\*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
SN74HCT257N	N	PDIP	16	25	506	13.97	11230	4.32
SN74HCT257N	N	PDIP	16	25	506	13.97	11230	4.32
SN74HCT257N.A	N	PDIP	16	25	506	13.97	11230	4.32
SN74HCT257N.A	N	PDIP	16	25	506	13.97	11230	4.32

# N (R-PDIP-T\*\*)

# PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



# D (R-PDS0-G16)

## PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AC.



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